

CSD01060–Silicon Carbide Schottky Diode

ZERO RECOVERY® RECTIFIER

$$\begin{aligned} V_{RRM} &= 600 \text{ V} \\ I_{F(AVG)} &= 1 \text{ A} \\ Q_c &= 3.3 \text{ nC} \end{aligned}$$

Features

- 600-Volt Schottky Rectifier
- Zero Reverse Recovery Current
- Zero Forward Recovery Voltage
- High-Frequency Operation
- Temperature-Independent Switching Behavior
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Rectifier Heat Sink
- Parallel Devices Without Thermal Runaway

Applications

- Switch Mode Power Supplies
- Power Factor Correction
 - Typical PFC P_{out} : 100W-200W
- Motor Drives
 - Typical Power : 0.25HP-0.5HP

Package



TO-252-2



TO-220-2



Part Number	Package	Marking
CSD01060A	TO-220-2	CSD01060
CSD01060E	TO-252-2	CSD01060

Maximum Ratings

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	600	V		
V_{RSM}	Surge Peak Reverse Voltage	600	V		
V_{DC}	DC Blocking Voltage	600	V		
$I_{F(AVG)}$	Average Forward Current	1.4 2.2	A	$T_C=150^\circ\text{C}$ $T_C=125^\circ\text{C}$	
$I_{F(PEAK)}$	Peak Forward Current	2.5	A	$T_C=125^\circ\text{C}$, $T_{REP}<1 \text{ mS}$, Duty=0.5	
I_{FRM}	Repetitive Peak Forward Surge Current	7 5.5	A	$T_C=25^\circ\text{C}$, $t_p=10 \text{ ms}$, Half Sine Wave $T_C=125^\circ\text{C}$, $t_p=10 \text{ ms}$, Half Sine Wave	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	9	A	$T_C=25^\circ\text{C}$, $t_p=1.5 \text{ ms}$, Half Sine Wave	
I_{FSM}	Non-Repetitive Peak Forward Surge Current	32	A	$T_C=25^\circ\text{C}$, $t_p=10 \mu\text{s}$, Pulse	
P_{tot}	Power Dissipation	21.4 7.1	W	$T_C=25^\circ\text{C}$ $T_C=125^\circ\text{C}$	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	$^\circ\text{C}$		
	TO-220 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	

Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.6 2.0	1.8 2.4	V	$I_F = 1\text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 1\text{ A}$ $T_J = 175^\circ\text{C}$	
I_R	Reverse Current	20 40	100 500	μA	$V_R = 600\text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 600\text{ V}$ $T_J = 150^\circ\text{C}$	
Q_C	Total Capacitive Charge	3.3		nC	$V_R = 600\text{ V}$, $I_F = 1\text{ A}$ $di/dt = 500\text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	
C	Total Capacitance	80 11 8.5		pF	$V_R = 0\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 200\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$ $V_R = 400\text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1\text{ MHz}$	

Note:

1. This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit
$R_{\theta JC}$	Thermal Resistance from Junction to Case	7	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance from Junction to Ambient	60	$^\circ\text{C}/\text{W}$

Typical Performance

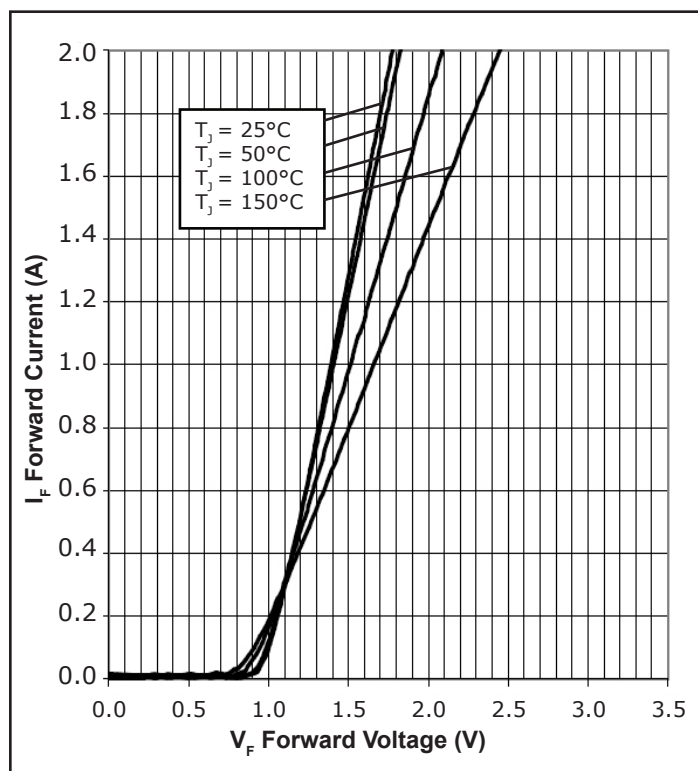


Figure 1. Forward Characteristics

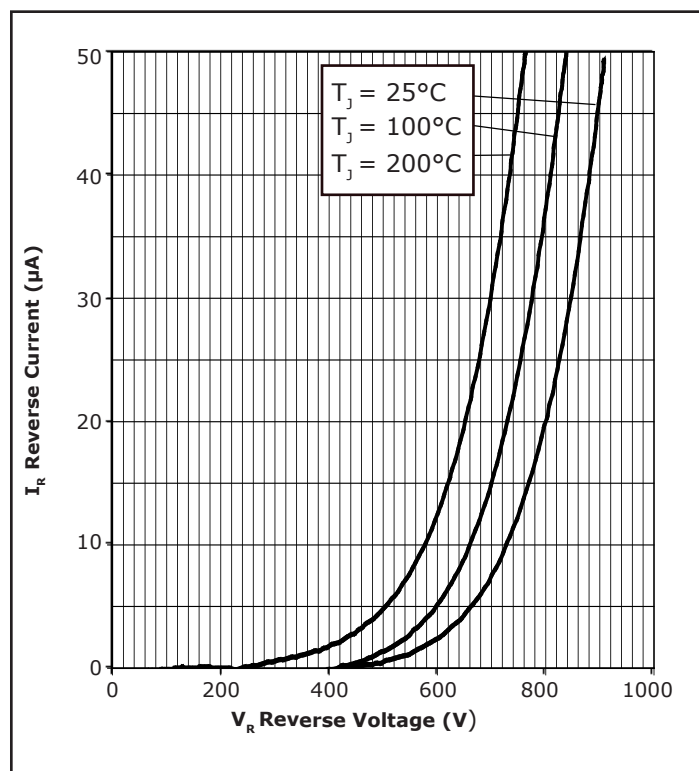


Figure 2. Reverse Characteristics

Typical Performance

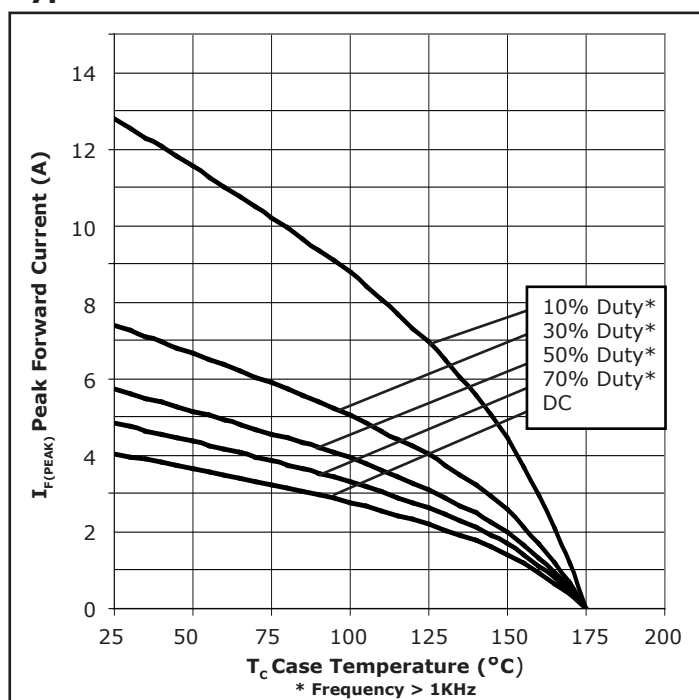


Figure 3. Current Derating

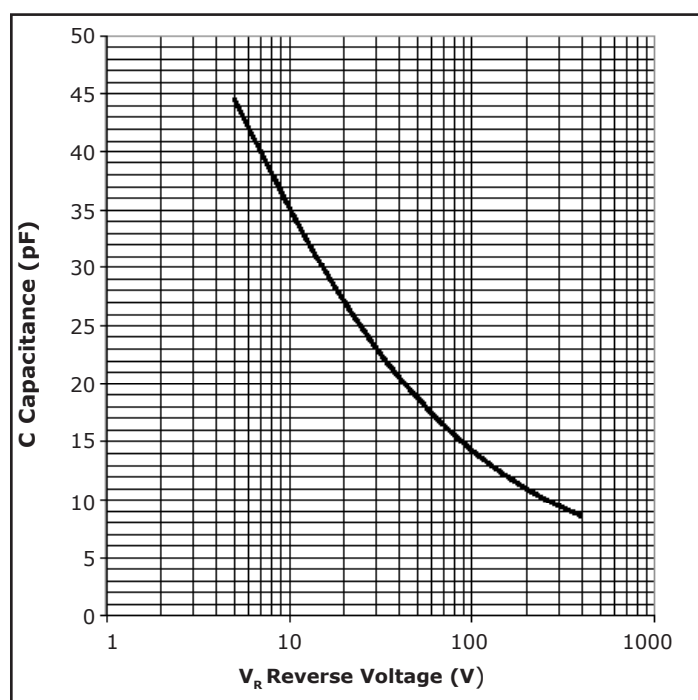


Figure 4. Capacitance vs. Reverse Voltage

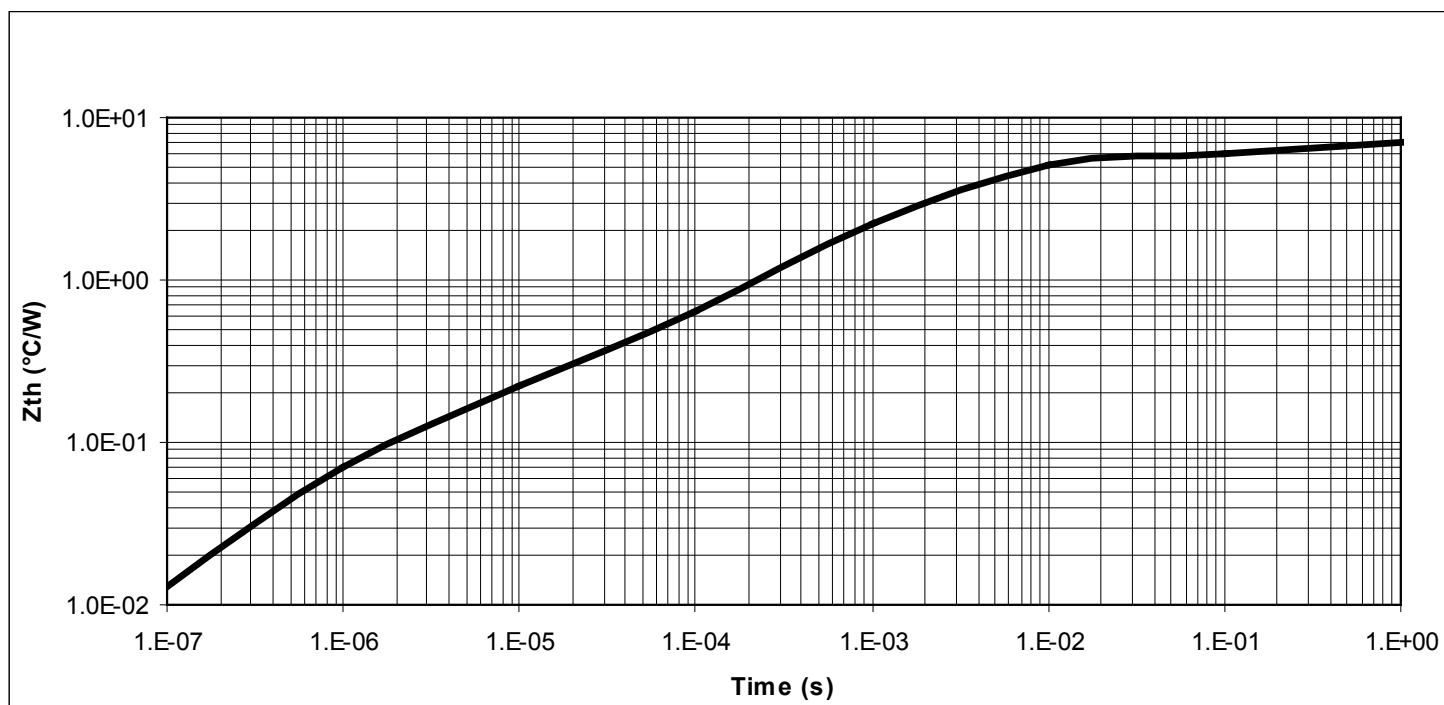


Figure 5. Transient Thermal Impedance

Typical Performance

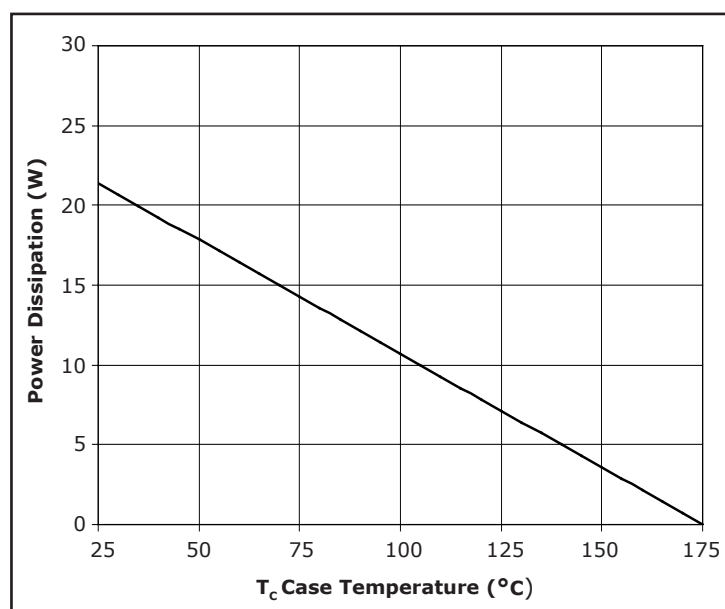
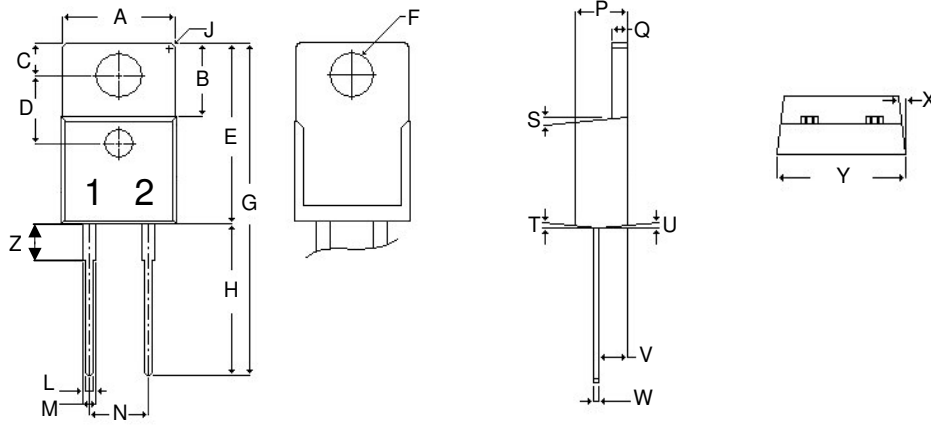


Figure 6. Power Derating

Package Dimensions

Package TO-220-2



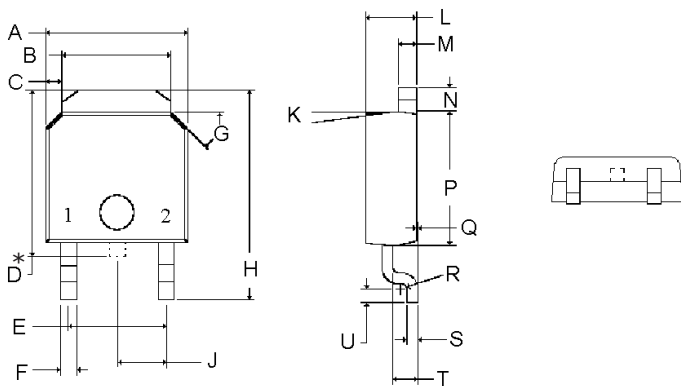
POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.381	.410	9.677	10.414
B	.235	.255	5.969	6.477
C	.100	.120	2.540	3.048
D	.223	.337	5.664	8.560
E	.590	.615	14.986	15.621
F	.143	.153	3.632	3.886
G	1.105	1.147	28.067	29.134
H	.500	.550	12.700	13.970
J	R 0.197		R 0.197	
L	.025	.036	.635	.914
M	.045	.055	1.143	1.397
N	.195	.205	4.953	5.207
P	.165	.185	4.191	4.699
Q	.048	.054	1.219	1.372
S	3°	6°	3°	6°
T	3°	6°	3°	6°
U	3°	6°	3°	6°
V	.094	.110	2.388	2.794
W	.014	.025	.356	.635
X	3°	5.5°	3°	5.5°
Y	.385	.410	9.779	10.414
z	.130	.150	3.302	3.810

NOTE:

1. Dimension L, M, W apply for Solder Dip Finish

Package Dimensions

Package TO-252-2

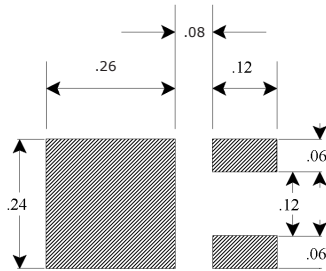


POS	Inches		Millimeters	
	Min	Max	Min	Max
A	.255	.265	6.477	6.731
B	.197	.205	5.004	5.207
C	.027	.033	.686	.838
D*	.270	.322	6.858	8.179
E	.178	.182	4.521	4.623
F	.025	.035	.635	.889
G	44°	46°	44°	46°
H	.382	.397	9.703	10.084
J	.090 TYP		2.286 TYP	
K	6°	8°	6°	8°
L	.086	.094	2.184	2.388
M	.030	.034	.762	.864
N	.040	.044	1.016	1.118
P	.235	.245	5.969	6.223
Q	0.00	.004	0.00	.102
R	R0.01 TYP		R0.31 TYP	
S	.017	.023	.428	.588
T	.040	.044	1.016	1.118
U	.021	.027	.534	1.118

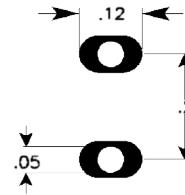
Note:

- * Tab "D" may not be present

Recommended Solder Pad Layout



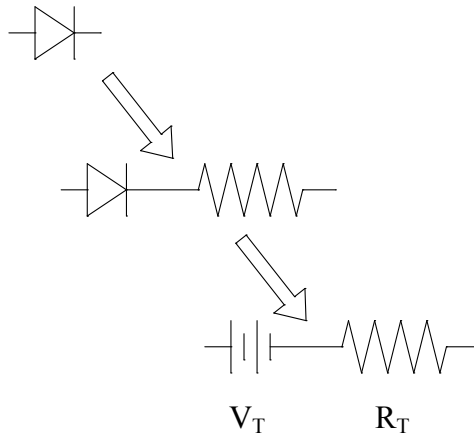
TO-252-2



TO-220-2

Part Number	Package	Marking
CSD01060A	TO-220-2	CSD01060
CSD01060E	TO-252-2	CSD01060

Diode Model



$$V_{fT} = V_T + I_f \cdot R_T$$

$$V_T = 0.94 + (T_j \cdot -1.2 \cdot 10^{-3})$$

$$R_T = 0.015 + (T_j \cdot 6.4 \cdot 10^{-3})$$

Note: T_j = Diode Junction Temperature In Degrees Celcius

"The levels of environmentally sensitive, persistent biologically toxic (PBT), persistent organic pollutants (POP), or otherwise restricted materials in this product are below the maximum concentration values (also referred to as the threshold limits) permitted for such substances, or are used in an exempted application, in accordance with EU Directive 2002/95/EC on the restriction of the use of certain hazardous substances in electrical and electronic equipment (RoHS), as amended through April 21, 2006. This part number was released previously with Sn/Pb solder plating as a standard industry finish. For more information please contact power_sales@cree.com "

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